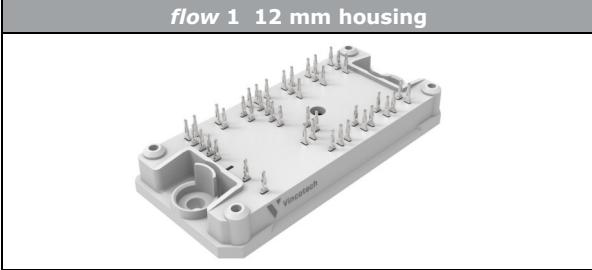
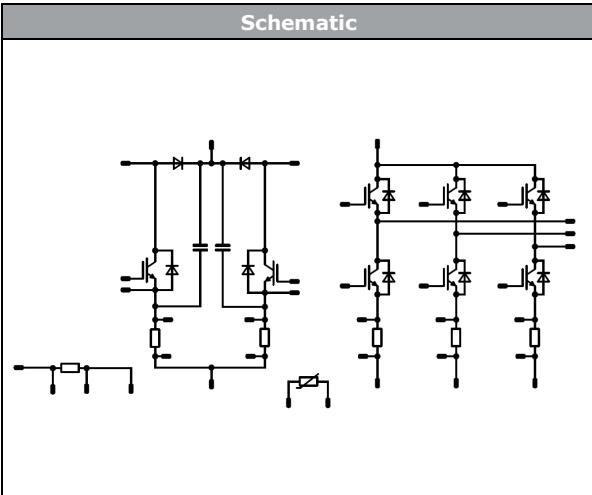




Vincotech

| flowPIM 1 + PFC | | 600 V / 50 A |
|----------------------------|--|---|
| Features | |  |
| | <ul style="list-style-type: none">• Highly integrated PIM with interleaved PFC circuit• High switching frequency PFC circuit• On-board capacitors• New generation high speed IGBTs in the inverter• Emitter shunts | |
| Target applications | | Schematic |
| | <ul style="list-style-type: none">• Embedded Drives• Industrial Drives |  |
| Types | | |
| | <ul style="list-style-type: none">• 10-PG06PPA050SJ01-LH54E08T | |

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Condition | Value | Unit |
|-----------------------------------|------------|--|----------|------------------|
| Inverter Switch | | | | |
| Collector-emitter voltage | V_{CES} | | 600 | V |
| Collector current | I_C | $T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ | 48 | A |
| Repetitive peak collector current | I_{CRM} | t_p limited by T_{jmax} | 150 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ | 81 | W |
| Gate-emitter voltage | V_{GES} | | ± 20 | V |
| Short circuit ratings | t_{SC} | $V_{GE} = 15\text{ V}$ $V_{CC} = 400\text{ V}$ $T_j = 150^\circ\text{C}$ | 5 | μs |
| Maximum junction temperature | T_{jmax} | | 175 | $^\circ\text{C}$ |



Vincotech

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Condition | Value | Unit |
|-------------------------------------|------------|---|----------|------------------|
| Inverter Diode | | | | |
| Peak repetitive reverse voltage | V_{RRM} | | 600 | V |
| Continuous (direct) forward current | I_F | $T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ | 35 | A |
| Repetitive peak forward current | I_{FRM} | | 60 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ | 58 | W |
| Maximum junction temperature | T_{jmax} | | 175 | $^\circ\text{C}$ |
| PFC Switch | | | | |
| Collector-emitter voltage | V_{CES} | | 650 | V |
| Collector current | I_C | $T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ | 47 | A |
| Repetitive peak collector current | I_{CRM} | t_p limited by T_{jmax} | 150 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ | 81 | W |
| Gate-emitter voltage | V_{GES} | | ± 20 | V |
| Maximum junction temperature | T_{jmax} | | 175 | $^\circ\text{C}$ |
| PFC Diode | | | | |
| Peak repetitive reverse voltage | V_{RRM} | | 650 | V |
| Continuous (direct) forward current | I_F | $T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ | 49 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ | 84 | W |
| Maximum junction temperature | T_{jmax} | | 175 | $^\circ\text{C}$ |
| PFC Sw. Protection Diode | | | | |
| Peak repetitive reverse voltage | V_{RRM} | | 650 | V |
| Continuous (direct) forward current | I_F | $T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ | 14 | A |
| Repetitive peak forward current | I_{FRM} | | 20 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ | 33 | W |
| Maximum junction temperature | T_{jmax} | | 175 | $^\circ\text{C}$ |
| Shunt | | | | |
| Max DC current | I_{MAX} | $T_c = 25^\circ\text{C}$ | 63 | A |
| Power dissipation | P_{tot} | $T_c = 70^\circ\text{C}$ | 4 | W |



Vincotech

Maximum Ratings

$T_j = 25 \text{ }^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Condition | Value | Unit |
|-----------|--------|-----------|-------|------|
|-----------|--------|-----------|-------|------|

PFC Shunt

| | | | | |
|--------------------|-----------|-----------------------------------|----|---|
| Maximum DC current | I_{MAX} | $T_c = 25 \text{ }^\circ\text{C}$ | 32 | A |
| Power dissipation | P_{tot} | $T_c = 70 \text{ }^\circ\text{C}$ | 2 | W |

Inverter Shunt

| | | | | |
|--------------------|-----------|-----------------------------------|----|---|
| Maximum DC current | I_{MAX} | $T_c = 25 \text{ }^\circ\text{C}$ | 32 | A |
| Power dissipation | P_{tot} | $T_c = 70 \text{ }^\circ\text{C}$ | 2 | W |

Capacitor (PFC)

| | | | | |
|-----------------------|-----------|--|------------|------------------|
| Maximum DC voltage | V_{MAX} | | 630 | V |
| Operation Temperature | T_{op} | | -55...+150 | $^\circ\text{C}$ |

Module Properties

Thermal Properties

| | | | | |
|---|-----------|--|---------------------------|------------------|
| Storage temperature | T_{stg} | | -40...+125 | $^\circ\text{C}$ |
| Operation temperature under switching condition | T_{op} | | -40...($T_{jmax} - 25$) | $^\circ\text{C}$ |

Isolation Properties

| | | | | | |
|----------------------------|------------|------------------|-----------------------|-----------|----|
| Isolation voltage | V_{isol} | DC Test Voltage* | $t_p = 2 \text{ s}$ | 6000 | V |
| | | AC Voltage | $t_p = 1 \text{ min}$ | 2500 | V |
| Creepage distance | | | | min. 12,7 | mm |
| Clearance | | | | 8,05 | mm |
| Comparative Tracking Index | CTI | | | > 200 | |

*100 % tested in production



Vincotech

Characteristic Values

| Parameter | Symbol | Conditions | | | | | | Value | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|-----|-------|-----|--|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_c [A] I_D [A] I_F [A] | T_j [°C] | Min | Typ | Max | | |

Inverter Switch

Static

| | | | | | | | | | | |
|--------------------------------------|--------------|---------------------|----|-----|--------|------------------|------|----------------------|-----|----|
| Gate-emitter threshold voltage | $V_{GE(th)}$ | $V_{GE} = V_{CE}$ | | | 0,0008 | 25 | 4,1 | 5,1 | 5,7 | V |
| Collector-emitter saturation voltage | V_{CESat} | | 15 | | 50 | 25 125 150 | | 1,48 1,60 1,64 | 1,8 | V |
| Collector-emitter cut-off current | I_{CES} | | 0 | 600 | | 25 | | | 2,8 | µA |
| Gate-emitter leakage current | I_{GES} | | 20 | 0 | | 25 | | | 100 | nA |
| Internal gate resistance | r_g | | | | | | | none | | Ω |
| Input capacitance | C_{ies} | $f = 1 \text{ Mhz}$ | 0 | 25 | 25 | 25 | 1950 | | | pF |
| Output capacitance | C_{oes} | | | | | | | | | |
| Reverse transfer capacitance | C_{res} | | | | | | | | | |
| Gate charge | Q_g | | 15 | 480 | 50 | 25 | | 249 | | nC |

Thermal

| | | | | | | | | | | |
|-------------------------------------|---------------|--|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{\text{paste}} = 3,4 \text{ W/mK}$ (PSX) | | | | | | 1,18 | | K/W |
|-------------------------------------|---------------|--|--|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|-----------------------------|--------------|--|----------|-----|----|------------------|--|-------------------------|--|-----|
| Turn-on delay time | $t_{d(on)}$ | $R_{gon} = 8 \Omega$ $R_{goff} = 8 \Omega$ | ± 15 | 350 | 50 | 25 125 150 | | 70 70 71 | | ns |
| Rise time | t_r | | | | | 25 125 150 | | 45 43 43 | | |
| Turn-off delay time | $t_{d(off)}$ | | | | | 25 125 150 | | 115 134 139 | | |
| Fall time | t_f | $Q_{rFWD} = 1,6 \mu\text{C}$ $Q_{rFWD} = 3,1 \mu\text{C}$ $Q_{rFWD} = 3,6 \mu\text{C}$ | ± 15 | 350 | 50 | 25 125 150 | | 22 34 41 | | mWs |
| Turn-on energy (per pulse) | E_{on} | | | | | 25 125 150 | | 1,838 2,198 2,277 | | |
| Turn-off energy (per pulse) | E_{off} | | | | | 25 125 150 | | 0,536 0,839 0,941 | | |



Vincotech

Characteristic Values

| Parameter | Symbol | Conditions | | | | | | Value | | | Unit |
|-----------|--------|------------|--------------|--------------|-----------|-----------|------------|-------|-----|-----|------|
| | | | V_{GE} [V] | V_{CE} [V] | I_c [A] | I_D [A] | T_j [°C] | Min | Typ | Max | |
| | | | V_{GS} [V] | V_{DS} [V] | I_F [A] | I_F [A] | | | | | |

Inverter Diode

Static

| | | | | | | | | | | |
|-------------------------|-------|--|--|-----|----|-----------|--|--------------|------|----|
| Forward voltage | V_F | | | | 30 | 25 150 | | 1,64 1,56 | 1,95 | V |
| Reverse leakage current | I_R | | | 600 | | 25 | | | 27 | µA |

Thermal

| | | | | | | | | | | |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX) | | | | | | 1,63 | | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|---------------------------------------|----------------------|---|----------|-----|----|-----|--|-------|--|------|
| Peak recovery current | I_{RRM} | $di/dt = 245 \text{ A/}\mu\text{s}$ $di/dt = 545 \text{ A/}\mu\text{s}$ $di/dt = 378 \text{ A/}\mu\text{s}$ | ± 15 | 350 | 50 | 25 | | 11 | | A |
| Reverse recovery time | t_{rr} | | | | | 125 | | 16 | | |
| | | | | | | 150 | | 17 | | |
| Recovered charge | Q_r | | | | | 25 | | 251 | | |
| | | | | | | 125 | | 332 | | |
| Reverse recovered energy | E_{rec} | | | | | 150 | | 393 | | ns |
| Peak rate of fall of recovery current | $(di_{rf}/dt)_{max}$ | | | | | 25 | | 1,615 | | |
| | | | | | | 125 | | 3,089 | | |
| | | | | | | 150 | | 3,567 | | µC |
| | | | | | | 25 | | 0,406 | | |
| | | | | | | 125 | | 0,762 | | |
| | | | | | | 150 | | 0,892 | | mWs |
| | | | | | | 25 | | 76 | | |
| | | | | | | 125 | | 88 | | |
| | | | | | | 150 | | 101 | | A/µs |



Vincotech

Characteristic Values

| Parameter | Symbol | Conditions | | | | | | Value | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|-----|-------|-----|--|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_c [A] I_D [A] I_F [A] | T_j [°C] | Min | Typ | Max | | |

PFC Switch

Static

| | | | | | | | | | | |
|--------------------------------------|--------------|---------------------|----|-----|--------|------------------|-----|----------------------|------|----|
| Gate-emitter threshold voltage | $V_{GE(th)}$ | $V_{GE} = V_{CE}$ | | | 0,0005 | 25 | 3,3 | 4 | 4,7 | V |
| Collector-emitter saturation voltage | V_{CESat} | | 15 | | 50 | 25 125 150 | | 1,51 1,65 1,69 | 2,22 | V |
| Collector-emitter cut-off current | I_{CES} | | 0 | 650 | | 25 | | | 40 | µA |
| Gate-emitter leakage current | I_{GES} | | 20 | 0 | | 25 | | | 120 | nA |
| Internal gate resistance | r_g | | | | | | | none | | Ω |
| Input capacitance | C_{ies} | $f = 1 \text{ Mhz}$ | 0 | 25 | 25 | 25 | | 3000 | | pF |
| Output capacitance | C_{oes} | | | | | | | 50 | | |
| Reverse transfer capacitance | C_{res} | | | | | | | 11 | | |
| Gate charge | Q_g | | 15 | 520 | 50 | 25 | | 120 | | nC |

Thermal

| | | | | | | | | | | |
|-------------------------------------|---------------|--|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{\text{paste}} = 3,4 \text{ W/mK}$ (PSX) | | | | | | 1,17 | | K/W |
|-------------------------------------|---------------|--|--|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|-----------------------------|--------------|--|--------|-----|----|-----|--|-------|--|-----|
| Turn-on delay time | $t_{d(on)}$ | $R_{gon} = 4 \Omega$ $R_{goff} = 4 \Omega$ | 0 / 15 | 400 | 50 | 25 | | 15 | | ns |
| Rise time | t_r | | | | | 125 | | 13 | | |
| | | | | | | 150 | | 15 | | |
| Turn-off delay time | $t_{d(off)}$ | | | | | 25 | | 6 | | |
| Fall time | t_f | $Q_{rFWD} = 0,9 \mu\text{C}$ $Q_{rFWD} = 1,8 \mu\text{C}$ $Q_{rFWD} = 2,3 \mu\text{C}$ | | | | 125 | | 7 | | mWs |
| Turn-on energy (per pulse) | E_{on} | | | | | 150 | | 8 | | |
| | | | | | | 25 | | 82 | | |
| Fall time | t_f | | | | | 125 | | 97 | | |
| | | $Q_{rFWD} = 0,9 \mu\text{C}$ $Q_{rFWD} = 1,8 \mu\text{C}$ $Q_{rFWD} = 2,3 \mu\text{C}$ | | | | 150 | | 101 | | |
| Turn-on energy (per pulse) | E_{on} | | | | | 25 | | 3 | | |
| | | | | | | 125 | | 6 | | |
| Fall time | t_f | | | | | 150 | | 8 | | |
| Turn-off energy (per pulse) | E_{off} | $Q_{rFWD} = 0,9 \mu\text{C}$ $Q_{rFWD} = 1,8 \mu\text{C}$ $Q_{rFWD} = 2,3 \mu\text{C}$ | | | | 25 | | 0,429 | | |
| | | | | | | 125 | | 0,668 | | |
| | | | | | | 150 | | 0,690 | | |
| | | | | | | 25 | | 0,152 | | |
| | | $Q_{rFWD} = 0,9 \mu\text{C}$ $Q_{rFWD} = 1,8 \mu\text{C}$ $Q_{rFWD} = 2,3 \mu\text{C}$ | | | | 125 | | 0,383 | | |
| | | | | | | 150 | | 0,471 | | |
| | | | | | | 25 | | | | |
| | | | | | | 125 | | | | |
| | | | | | | 150 | | | | |



10-PG06PPA050SJ01-LH54E08T

datasheet

Vincotech

Characteristic Values

| Parameter | Symbol | Conditions | | | | | | Value | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|-----|-------|-----|--|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_c [A] I_D [A] I_F [A] | T_j [°C] | Min | Typ | Max | | |

PFC Diode

Static

| | | | | | | | | | | |
|-------------------------|-------|--|--|-----|----|------------------|--|----------------------|-----|----|
| Forward voltage | V_F | | | | 50 | 25 125 150 | | 2,17 1,87 1,80 | 2,6 | V |
| Reverse leakage current | I_R | | | 650 | | 25 | | | 10 | µA |

Thermal

| | | | | | | | | | | |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX) | | | | | | 1,14 | | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|---------------------------------------|----------------------|--|--------|-----|----|-----|--|-------|--|------|
| Peak recovery current | I_{RRM} | $di/dt = 6122 \text{ A/}\mu\text{s}$ $di/dt = 5344 \text{ A/}\mu\text{s}$ $di/dt = 4864 \text{ A/}\mu\text{s}$ | 0 / 15 | 400 | 50 | 25 | | 63 | | A |
| Reverse recovery time | t_{rr} | | | | | 125 | | 83 | | |
| Recovered charge | Q_r | | | | | 150 | | 92 | | |
| Reverse recovered energy | E_{rec} | | | | | 25 | | 17 | | |
| Peak rate of fall of recovery current | $(di_{rf}/dt)_{max}$ | | | | | 125 | | 47 | | ns |
| | | | | | | 150 | | 54 | | |
| | | | | | | 25 | | 0,941 | | |
| | | | | | | 125 | | 1,793 | | µC |
| | | | | | | 150 | | 2,268 | | |
| | | | | | | 25 | | 0,212 | | |
| | | | | | | 125 | | 0,370 | | mWs |
| | | | | | | 150 | | 0,547 | | |
| | | | | | | 25 | | 14126 | | |
| | | | | | | 125 | | 8573 | | A/µs |
| | | | | | | 150 | | 6729 | | |

PFC Sw. Protection Diode

Static

| | | | | | | | | | | |
|-------------------------|-------|--|--|-----|----|-----------|--|--------------|------|----|
| Forward voltage | V_F | | | | 10 | 25 125 | | 1,67 1,56 | 1,87 | V |
| Reverse leakage current | I_R | | | 650 | | 25 | | | 0,14 | µA |

Thermal

| | | | | | | | | | | |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX) | | | | | | 2,87 | | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|

Shunt

| | | | | | | | | | | |
|-------------------------|------|--|--|--|--|---------|--|----|--|-------|
| Resistance | R | | | | | | | 1 | | mΩ |
| Tolerance* | | | | | | | | 1 | | % |
| Temperature coefficient | tc | | | | | 20 - 60 | | 75 | | ppm/K |

* Nominal tolerance of the component as shown in manufacturer's datasheet. **Not tested in production**



Vincotech

Characteristic Values

| Parameter | Symbol | Conditions | | | | | | Value | | | Unit |
|-----------|--------|--------------|--------------|-----------|-----------|------------|-----|-------|-----|--|------|
| | | V_{GE} [V] | V_{CE} [V] | I_c [A] | I_D [A] | T_1 [°C] | Min | Typ | Max | | |
| | | V_{GS} [V] | V_{DS} [V] | I_F [A] | | | | | | | |

PFC Shunt

| | | | | | | | | | | |
|-------------------------|------|--|--|--|---------|--|--|----|--|------------------|
| Resistance | R | | | | | | | 2 | | $\text{m}\Omega$ |
| Tolerance | | | | | | | | 1 | | % |
| Temperature coefficient | tc | | | | 20 - 60 | | | 75 | | ppm/K |

* Nominal tolerance of the component as shown in manufacturer's datasheet. **Not tested in production**

Inverter Shunt

| | | | | | | | | | | |
|-------------------------|------|--|--|--|---------|--|--|----|--|------------------|
| Resistance | R | | | | | | | 2 | | $\text{m}\Omega$ |
| Tolerance | | | | | | | | 1 | | % |
| Temperature coefficient | tc | | | | 20 - 60 | | | 75 | | ppm/K |

* Nominal tolerance of the component as shown in manufacturer's datasheet. **Not tested in production**

Capacitor (PFC)

| | | | | | | | | | | |
|-------------|-----|--|--|--|--|--|----|----|----|-------------|
| Capacitance | C | | | | | | | 33 | | nF |
| Tolerance | | | | | | | -5 | | +5 | % |

Thermistor

| | | | | | | | | | | |
|----------------------------|----------------|-------------------------|--|--|-----|----|------|---|--|------------------|
| Rated resistance | R | | | | 25 | | 22 | | | $\text{k}\Omega$ |
| Deviation of R_{100} | $\Delta R/R$ | $R_{100} = 1484 \Omega$ | | | 100 | -5 | | 5 | | % |
| Power dissipation | P | | | | 25 | | 5 | | | mW |
| Power dissipation constant | | | | | 25 | | 1,5 | | | mW/K |
| B-value | $B_{(25/50)}$ | Tol. $\pm 1\%$ | | | 25 | | 3962 | | | K |
| B-value | $B_{(25/100)}$ | Tol. $\pm 1\%$ | | | 25 | | 4000 | | | K |
| Vincotech NTC Reference | | | | | | | | I | | |



Vincotech

Inverter Switch Characteristics

figure 1. IGBT

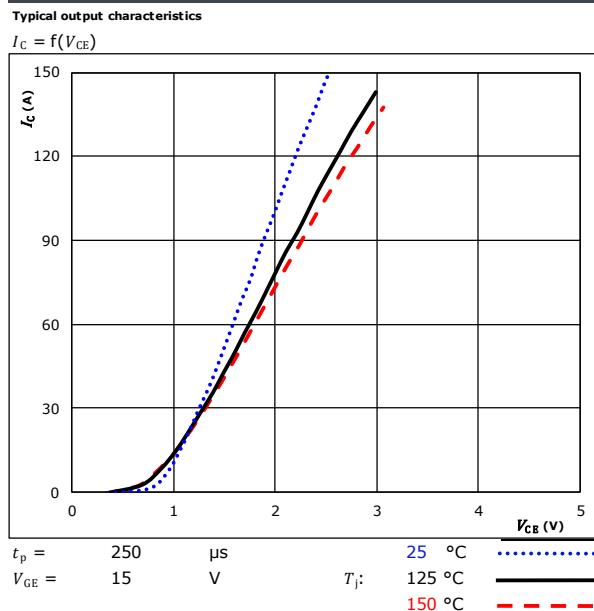


figure 2. IGBT

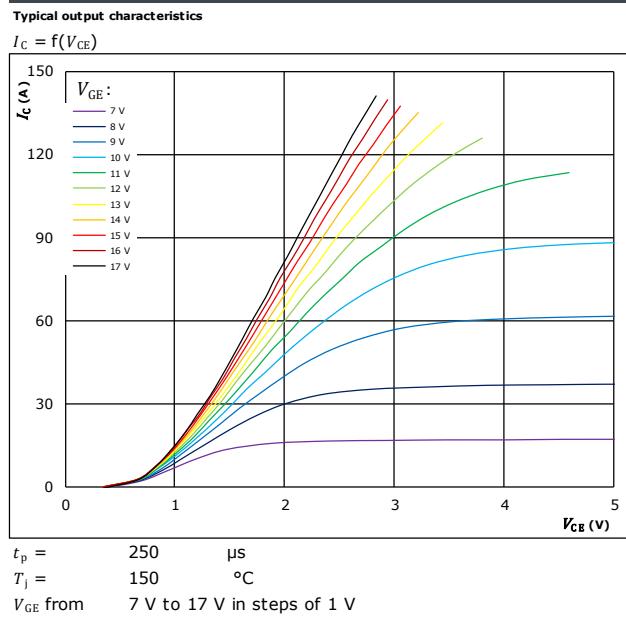


figure 3. IGBT

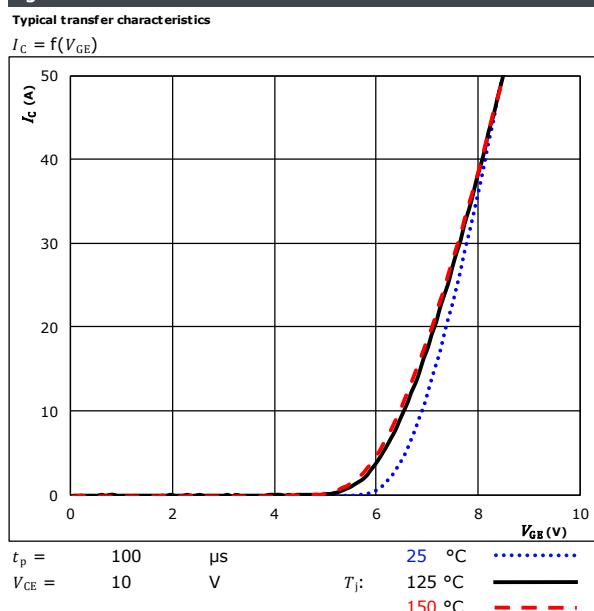
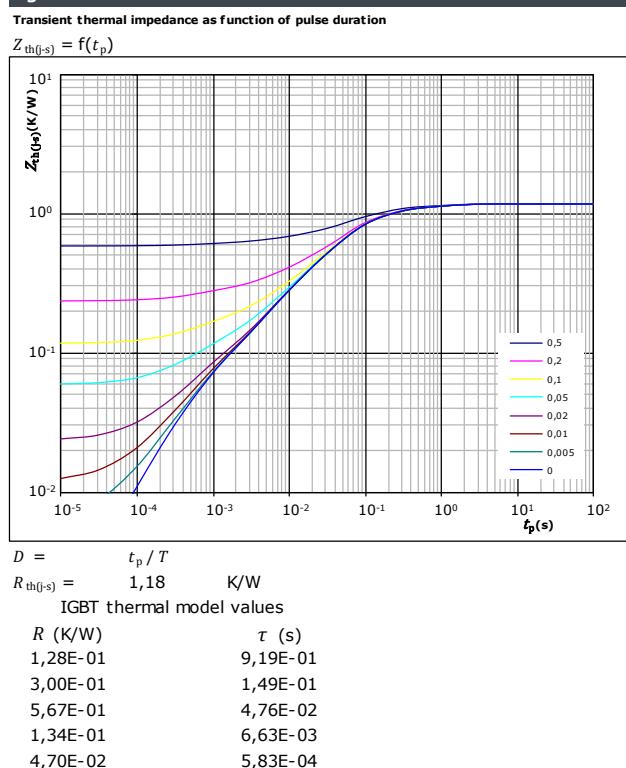


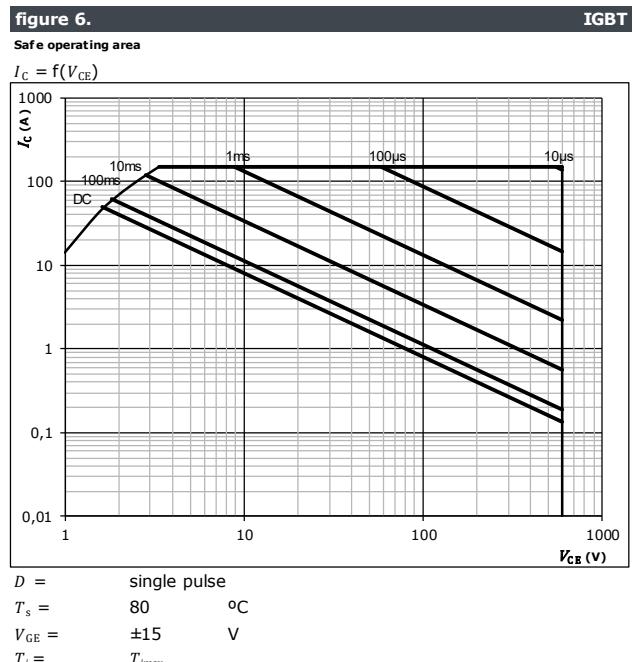
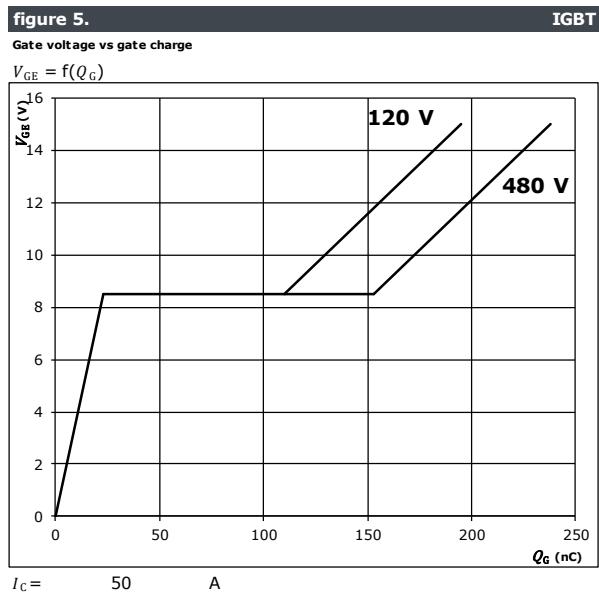
figure 4. IGBT





Vincotech

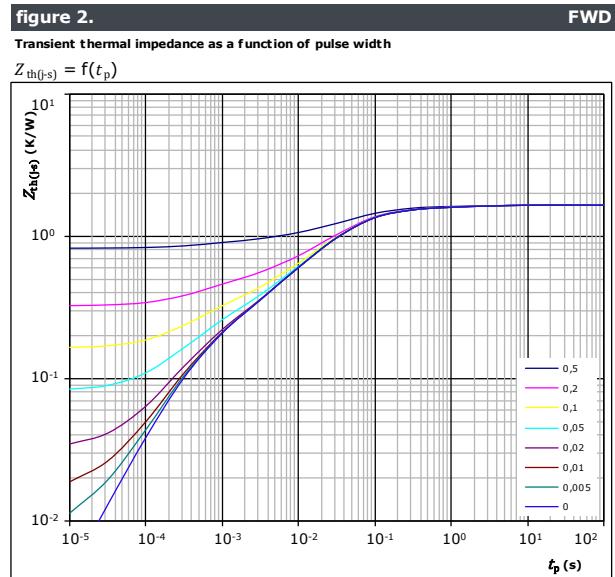
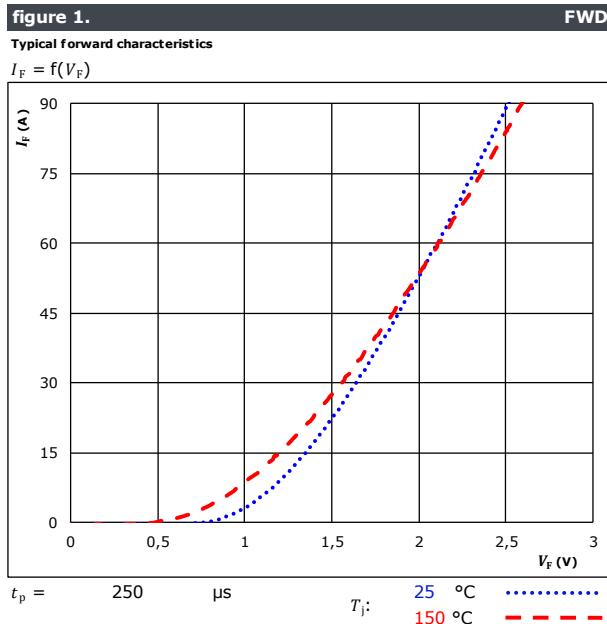
Inverter Switch Characteristics





Vincotech

Inverter Diode Characteristics



FWD thermal model values

| R (K/W) | τ (s) |
|-----------|------------|
| 7,13E-02 | 2,56E+00 |
| 1,55E-01 | 2,86E-01 |
| 7,25E-01 | 5,21E-02 |
| 3,93E-01 | 1,46E-02 |
| 1,57E-01 | 2,62E-03 |
| 1,32E-01 | 3,83E-04 |



Vincotech

PFC Switch Characteristics

figure 1. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

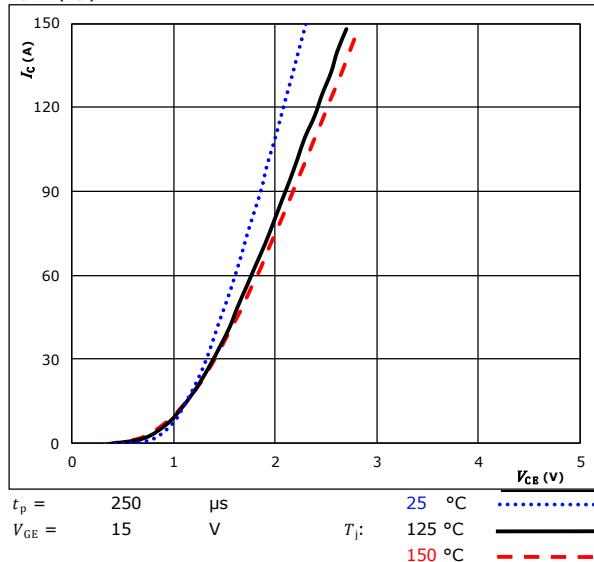


figure 2. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

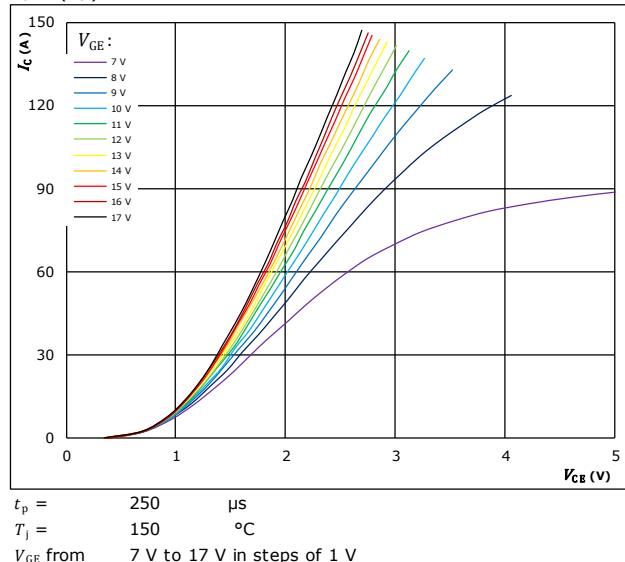


figure 3. IGBT

Typical transfer characteristics

$$I_C = f(V_{GE})$$

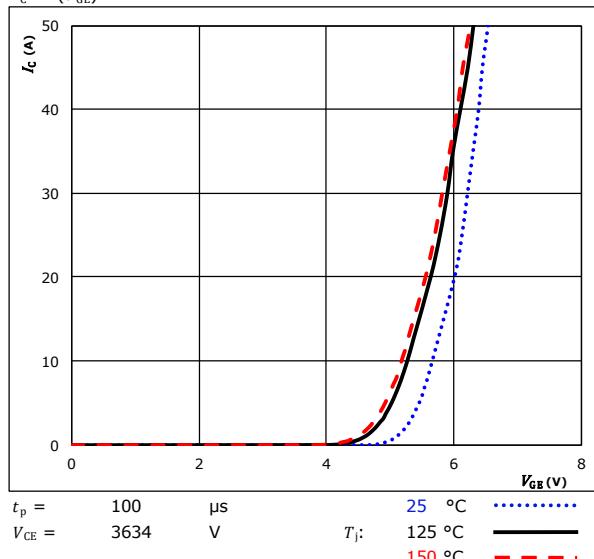
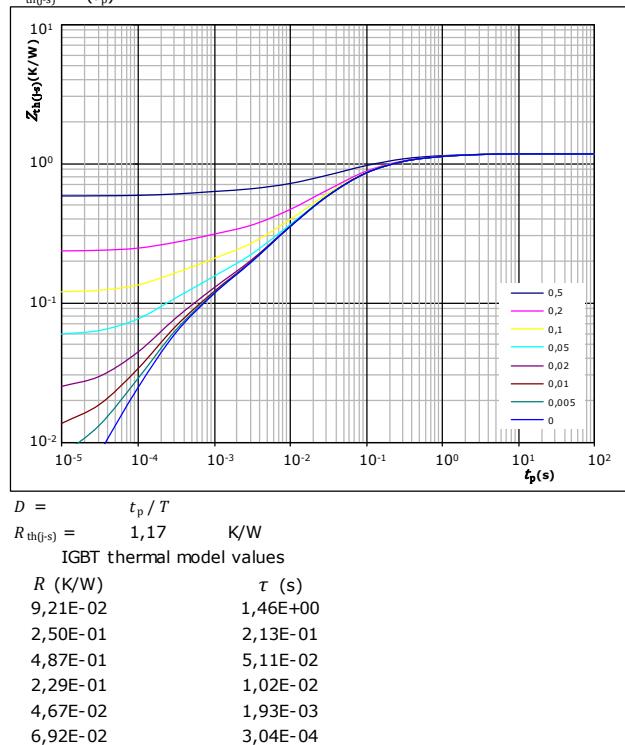


figure 4. IGBT

Transient thermal impedance as function of pulse duration

$$Z_{th(j-s)} = f(t_p)$$





10-PG06PPA050SJ01-LH54E08T

datasheet

Vincotech

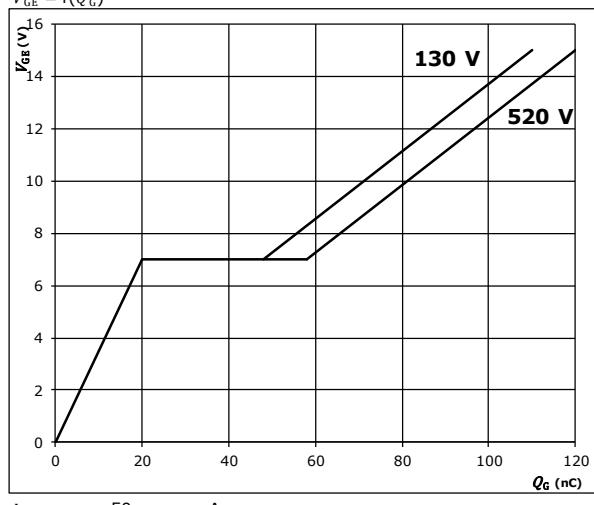
PFC Switch Characteristics

figure 5.

IGBT

Gate voltage vs gate charge

$$V_{GE} = f(Q_G)$$



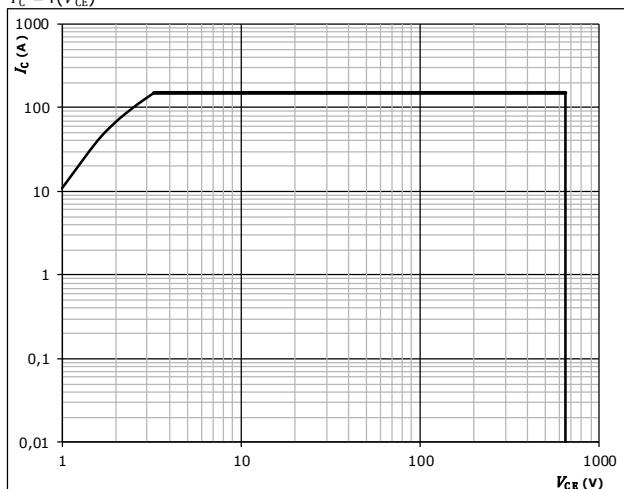
$$I_C = 50 \text{ A}$$

figure 6.

IGBT

Safe operating area

$$I_C = f(V_{CE})$$



$$D = \text{single pulse}$$

$$T_s = 80 \text{ } ^\circ\text{C}$$

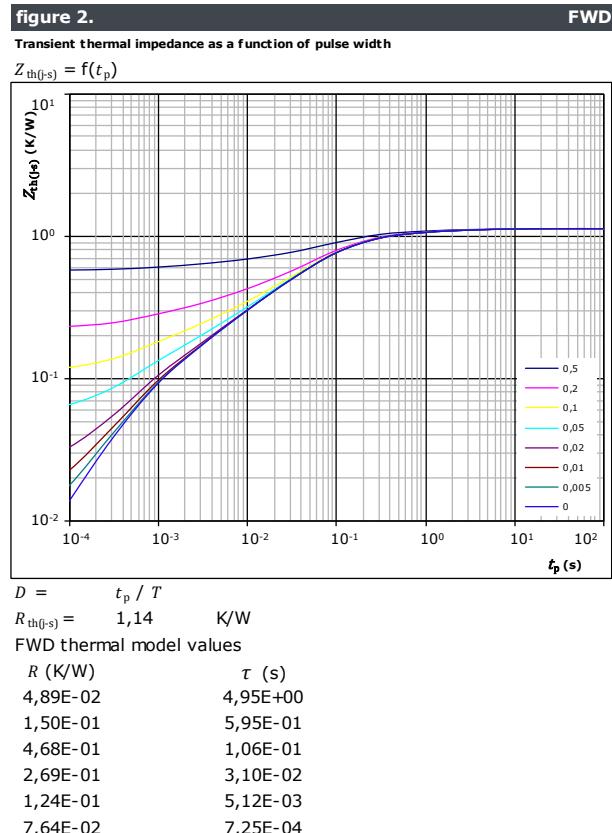
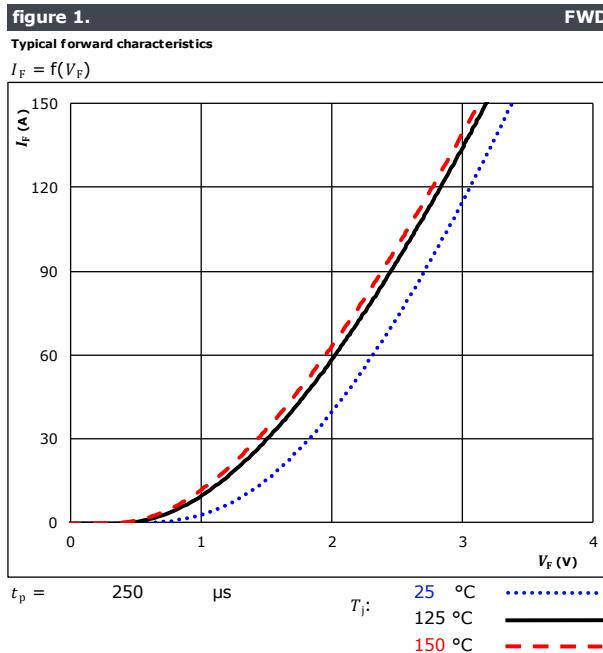
$$V_{GE} = \pm 15 \text{ V}$$

$$T_j = T_{jmax}$$



Vincotech

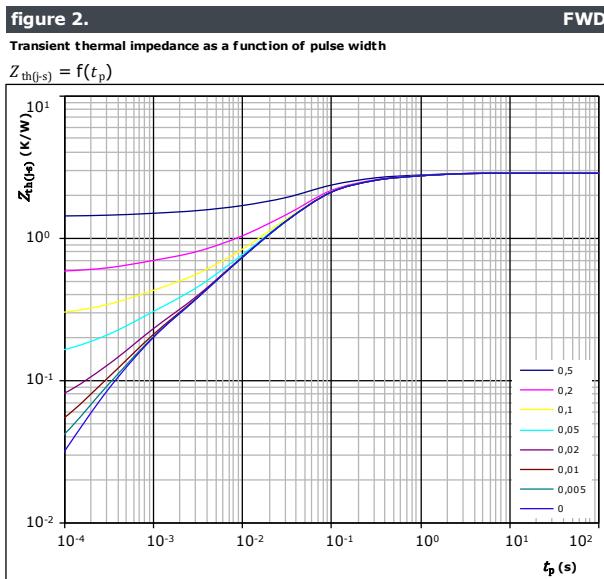
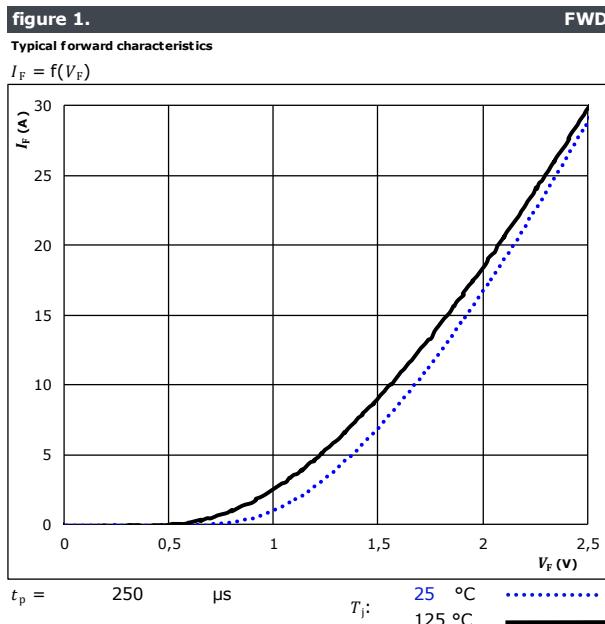
PFC Diode Characteristics





Vincotech

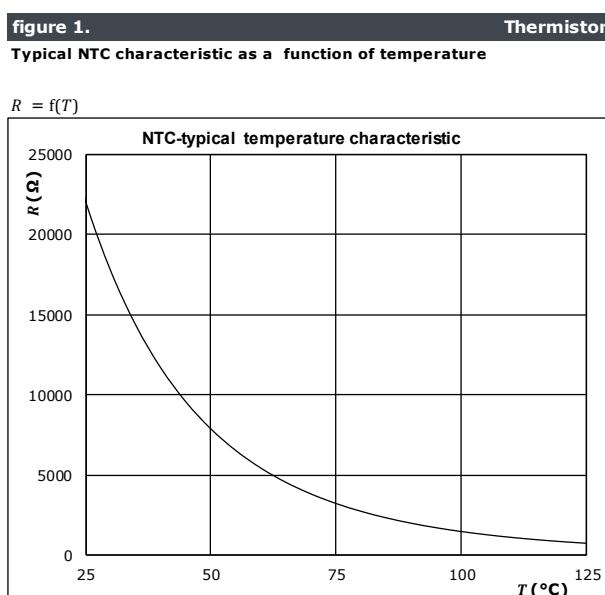
PFC Sw. Protection Diode Characteristics



FWD thermal model values

| R (K/W) | τ (s) |
|-----------|------------|
| 2,86E-01 | 2,80E+00 |
| 5,75E-01 | 4,47E-01 |
| 1,57E+00 | 1,18E-01 |
| 3,05E-01 | 1,46E-02 |
| 1,34E-01 | 1,45E-03 |

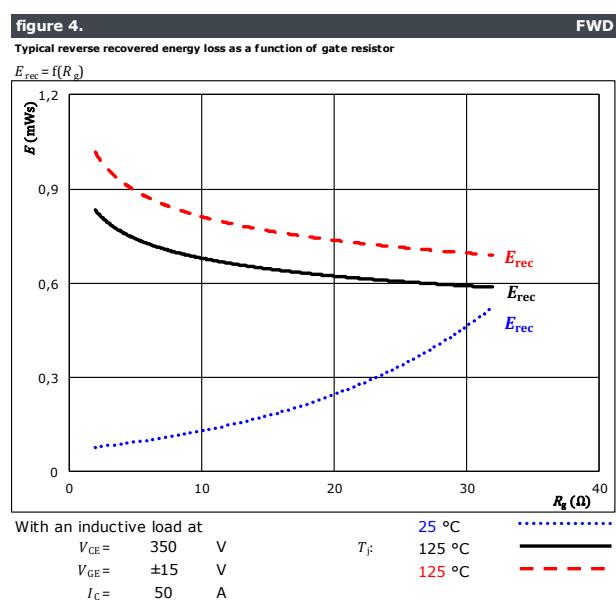
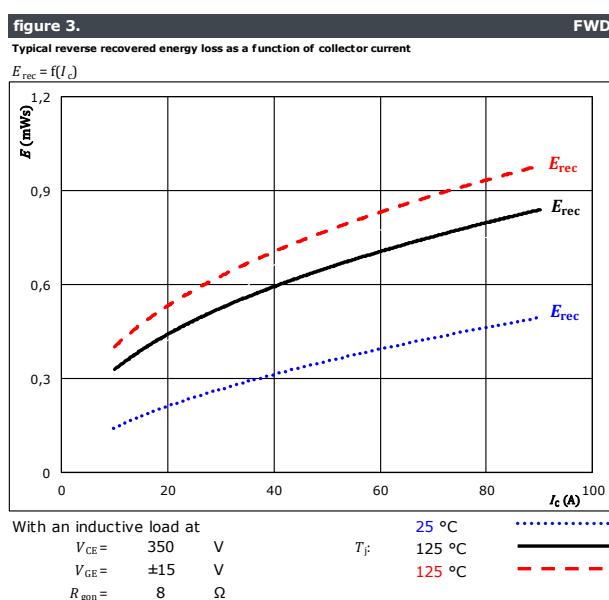
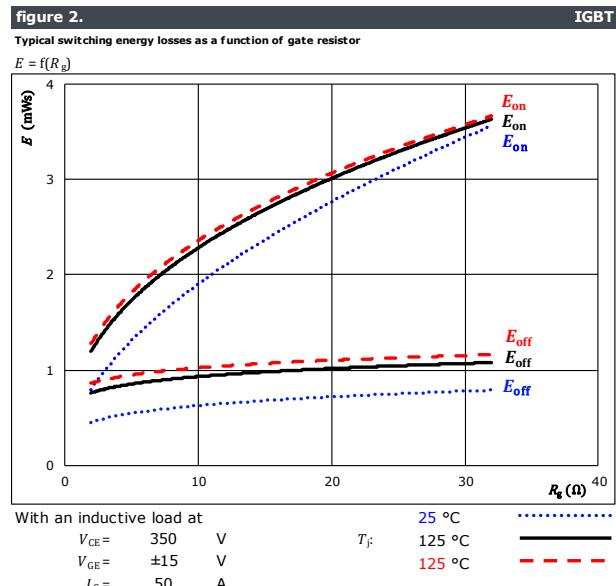
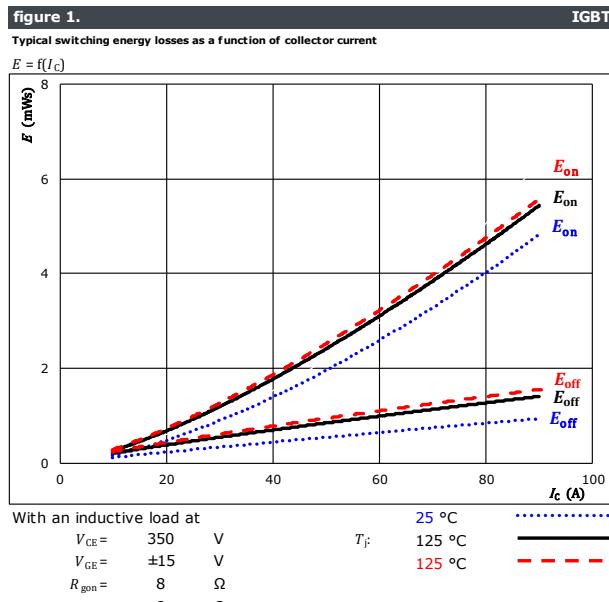
Thermistor Characteristics





Vincotech

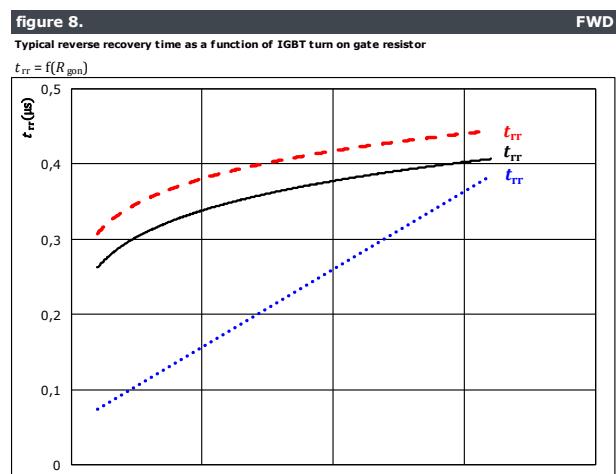
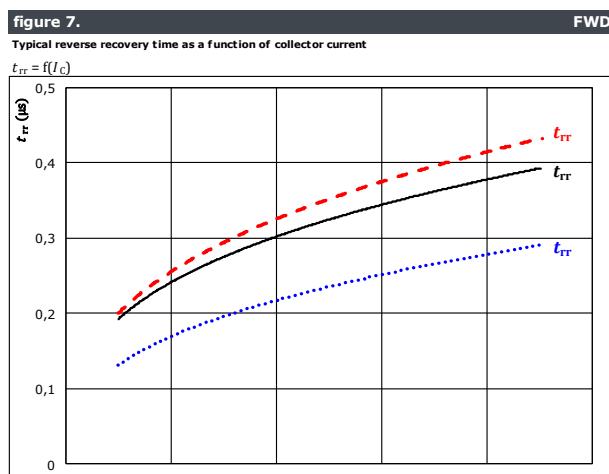
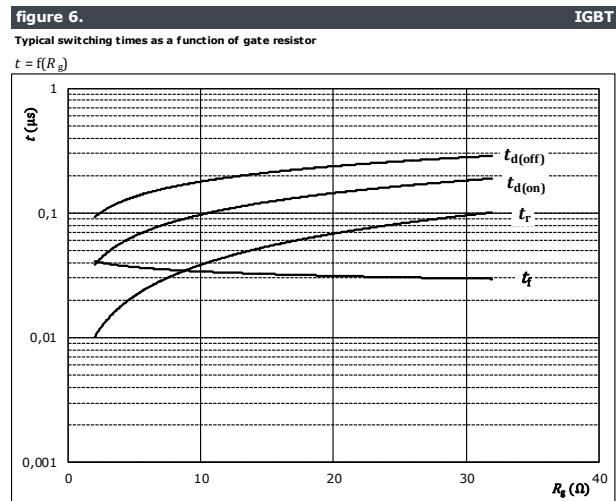
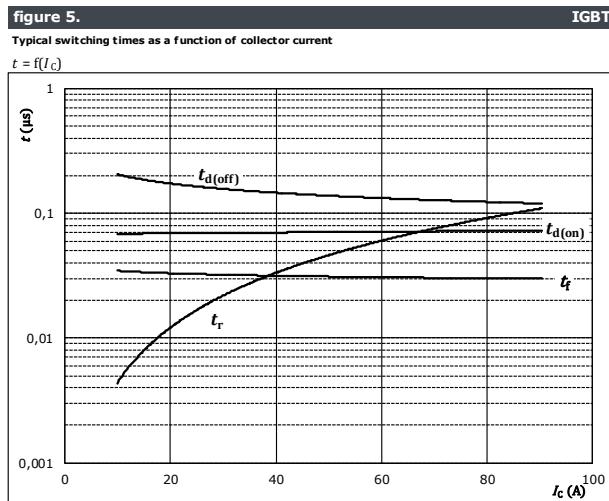
Inverter Switching Characteristics





Vincotech

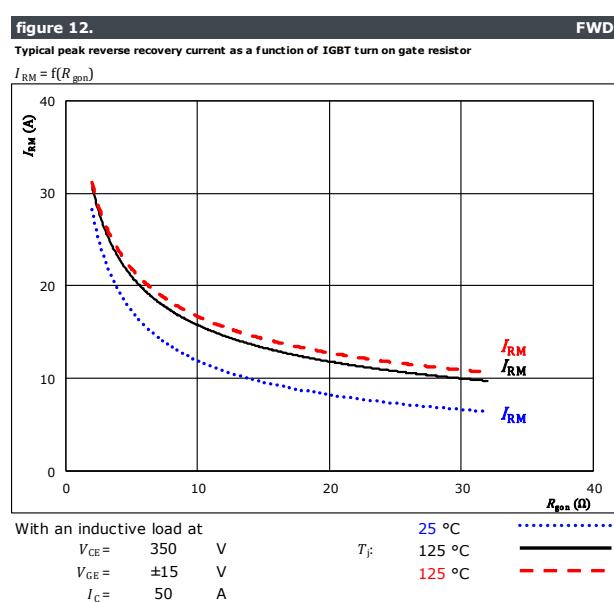
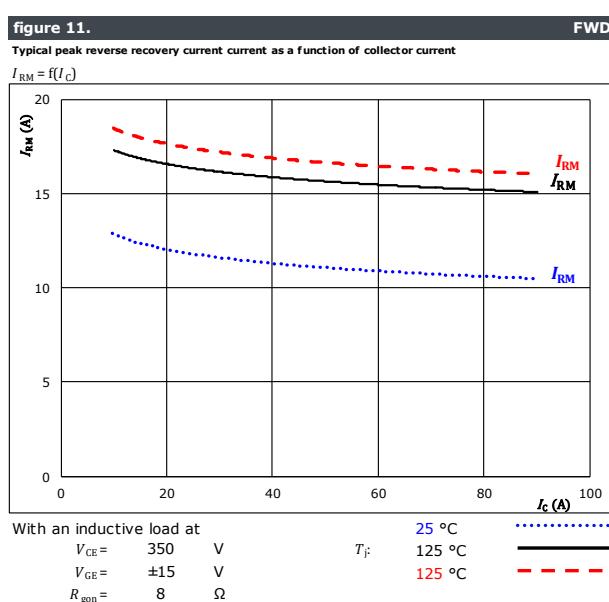
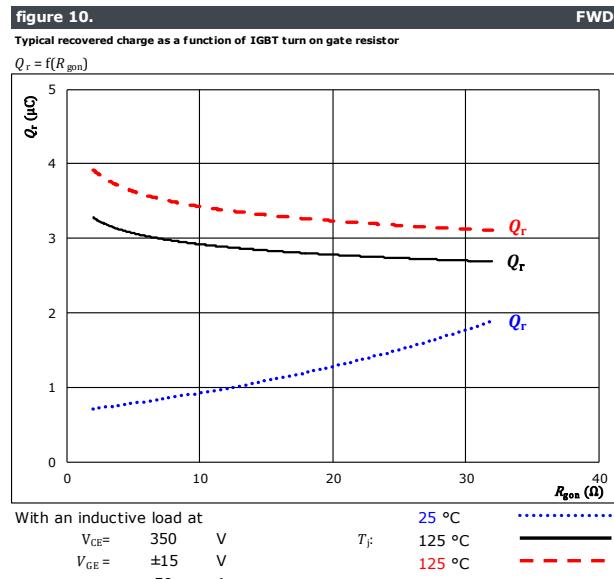
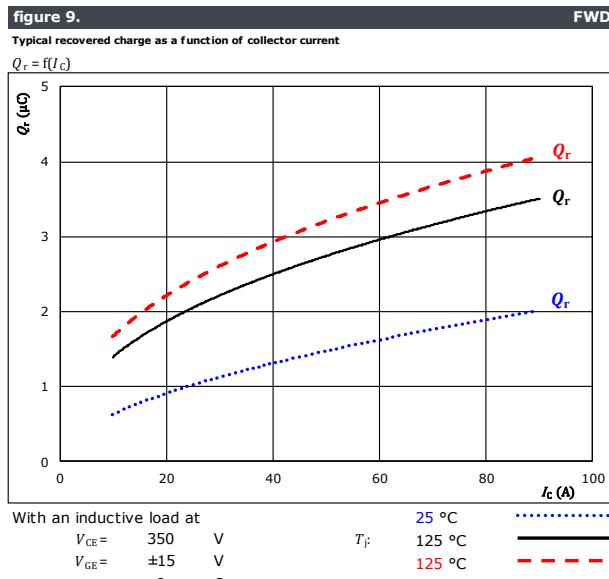
Inverter Switching Characteristics





Vincotech

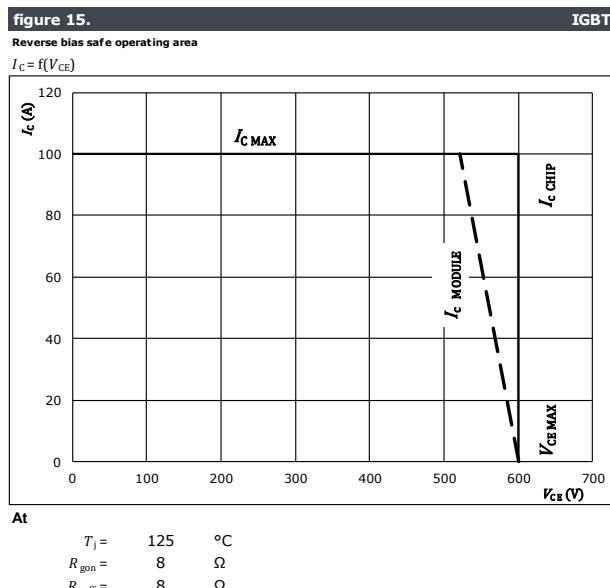
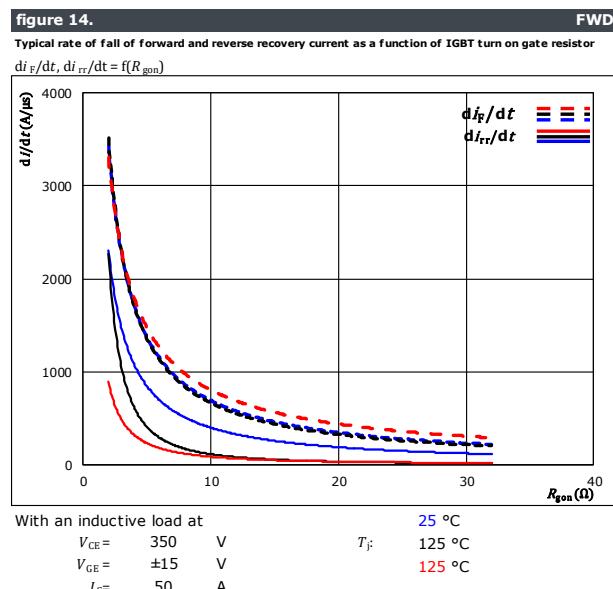
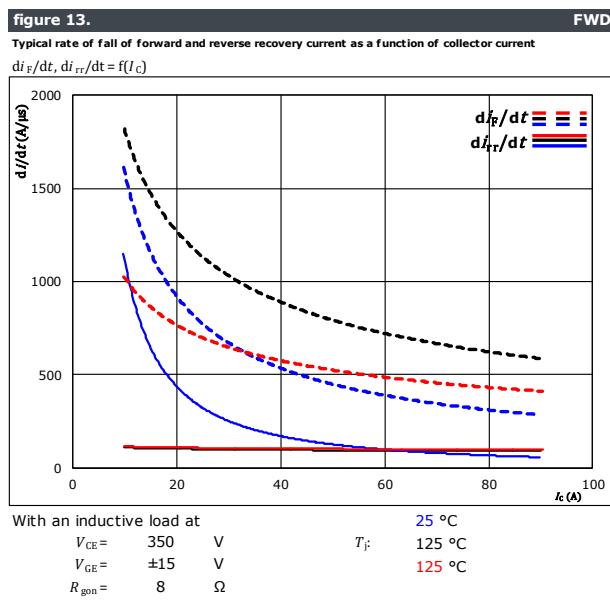
Inverter Switching Characteristics





Vincotech

Inverter Switching Characteristics



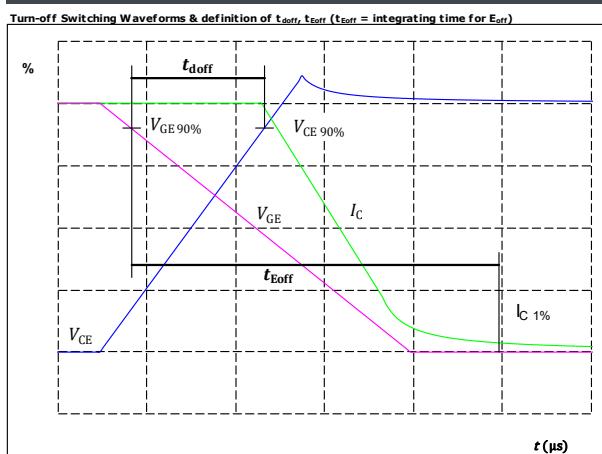


Vincotech

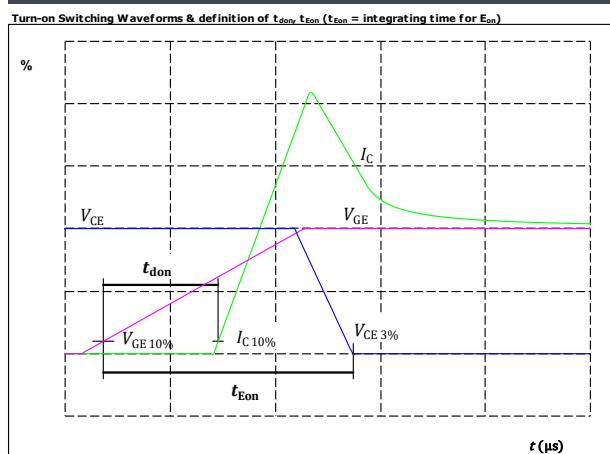
Inverter Switching Definitions

General conditions

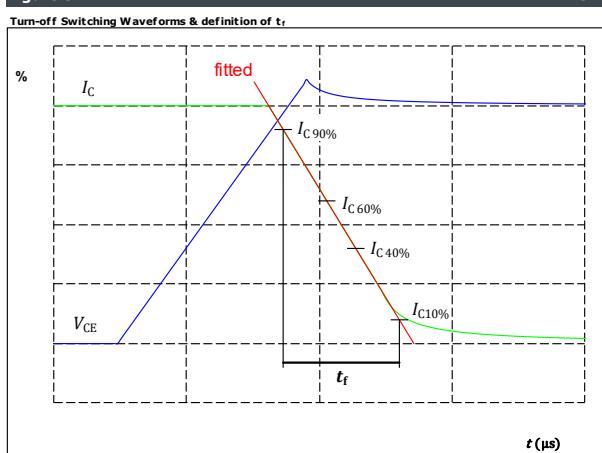
| | | |
|------------|---|--------|
| T_j | = | 125 °C |
| R_{gon} | = | 8 Ω |
| R_{goff} | = | 8 Ω |

figure 1.**IGBT**

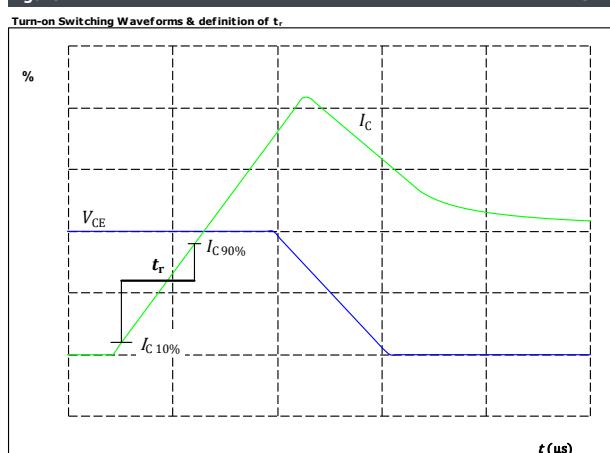
$V_{GE}(0\%) = -15 \text{ V}$
 $V_{GE}(100\%) = 15 \text{ V}$
 $V_C(100\%) = 350 \text{ V}$
 $I_C(100\%) = 50 \text{ A}$
 $t_{doff} = 134 \text{ ns}$

figure 2.**IGBT**

$V_{GE}(0\%) = -15 \text{ V}$
 $V_{GE}(100\%) = 15 \text{ V}$
 $V_C(100\%) = 350 \text{ V}$
 $I_C(100\%) = 50 \text{ A}$
 $t_{don} = 70 \text{ ns}$

figure 3.**IGBT**

$V_C(100\%) = 350 \text{ V}$
 $I_C(100\%) = 50 \text{ A}$
 $t_f = 34 \text{ ns}$

figure 4.**IGBT**

$V_{GE}(0\%) = -15 \text{ V}$
 $V_{GE}(100\%) = 15 \text{ V}$
 $V_C(100\%) = 350 \text{ V}$
 $I_C(100\%) = 50 \text{ A}$
 $t_r = 43 \text{ ns}$



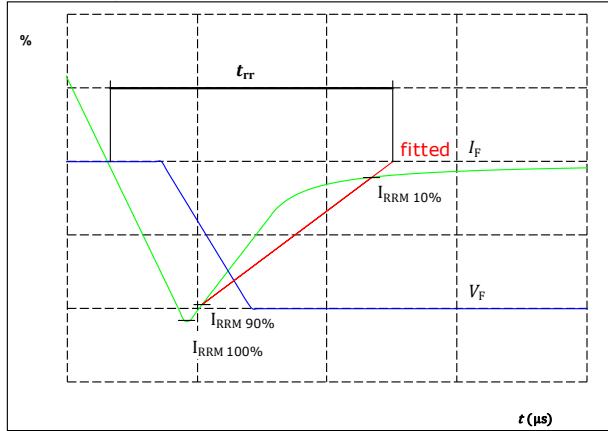
Vincotech

Inverter Switching Characteristics

figure 5.

FWD

Turn-off Switching Waveforms & definition of t_{rr}

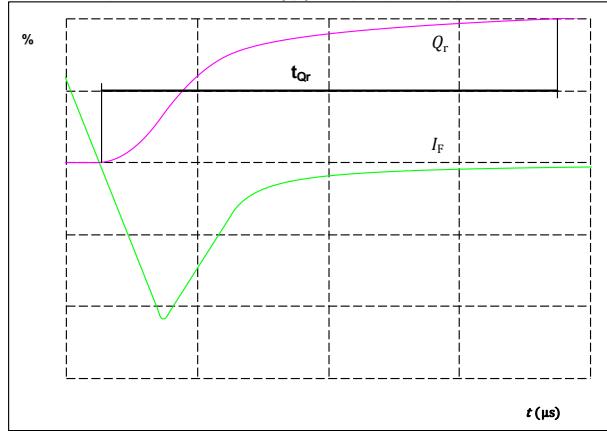


| | | |
|--------------------|-----|----|
| $V_F(100\%) =$ | 350 | V |
| $I_F(100\%) =$ | 50 | A |
| $I_{RRM}(100\%) =$ | 16 | A |
| $t_{rr} =$ | 332 | ns |

figure 6.

FWD

Turn-on Switching Waveforms & definition of t_{qr} (t_{qr} = integrating time for Q_r)

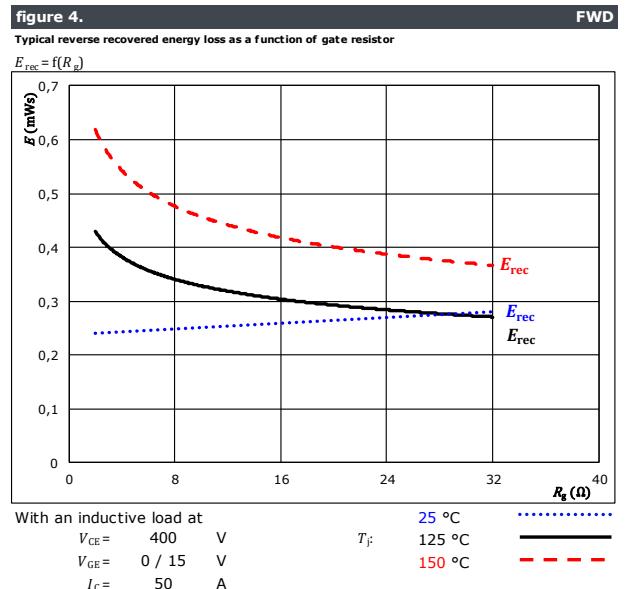
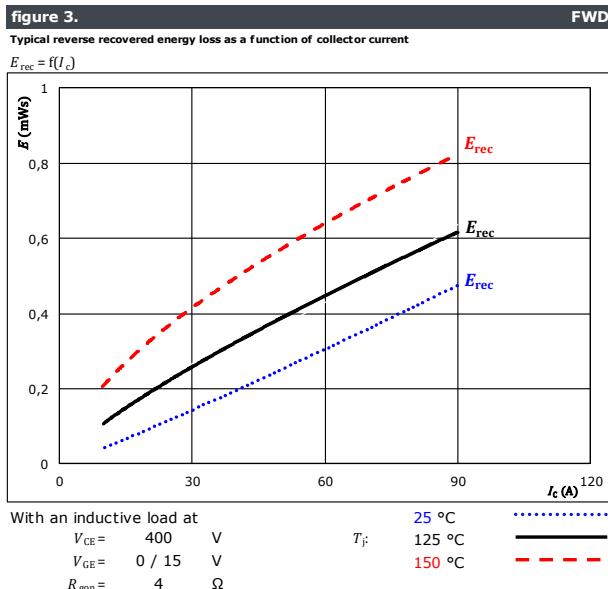
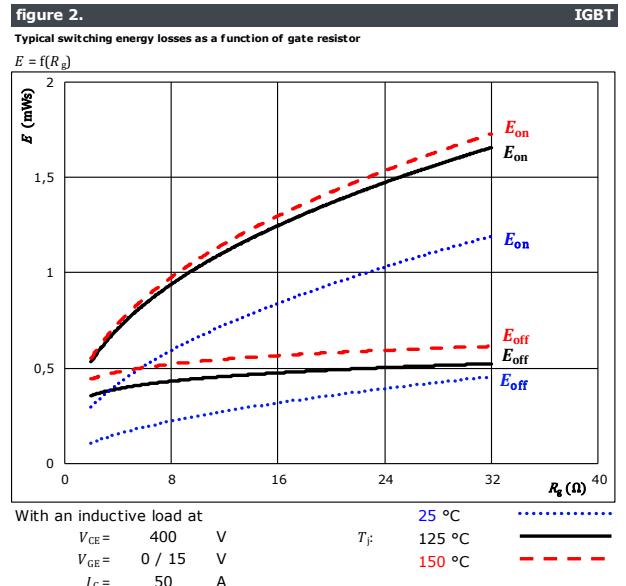
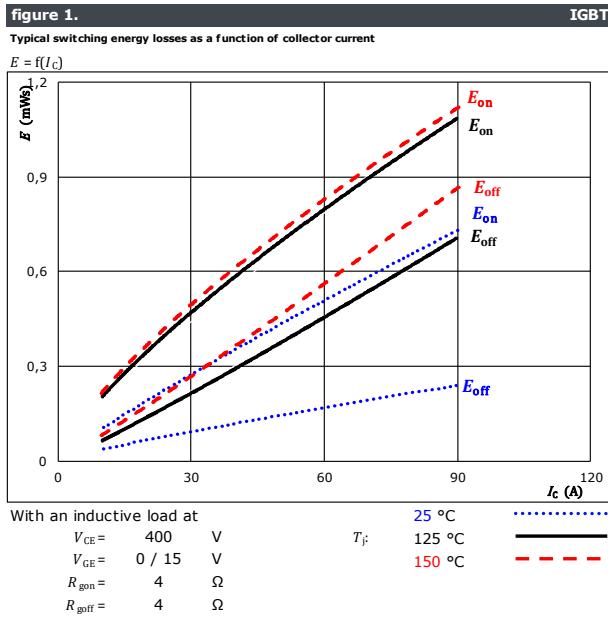


| | | |
|----------------|------|----|
| $I_F(100\%) =$ | 50 | A |
| $Q_r(100\%) =$ | 3,09 | μC |



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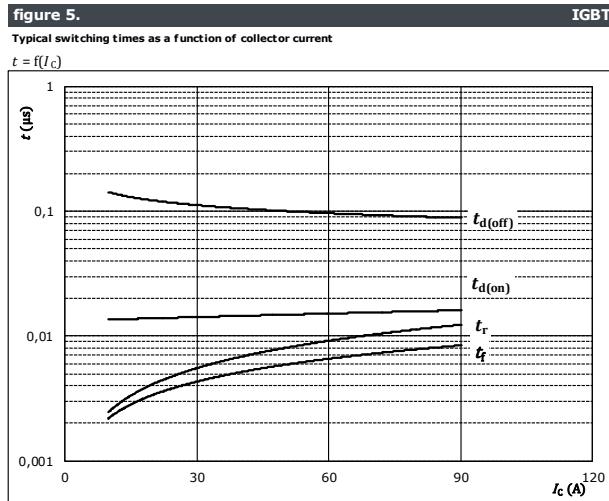
PFC Switching Characteristics





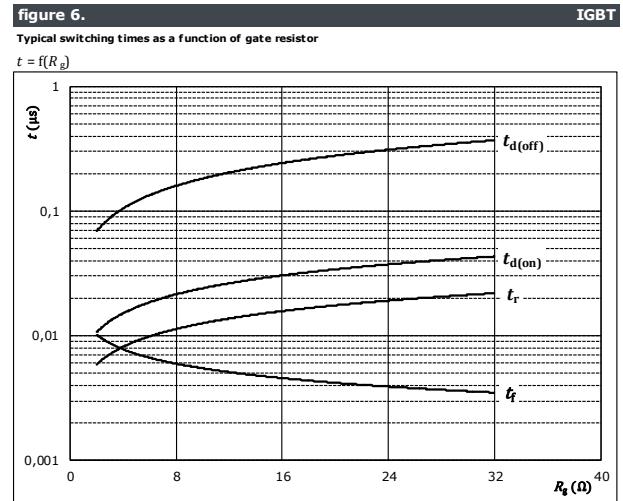
Vincotech

PFC Switching Characteristics



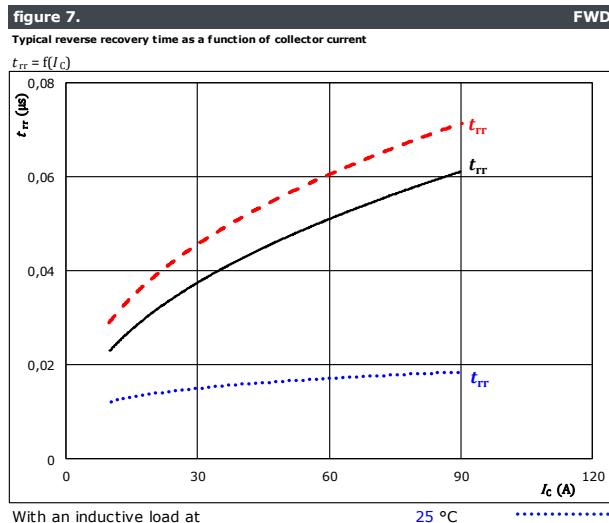
With an inductive load at

| | | |
|--------------|--------|----|
| $T_j =$ | 150 | °C |
| $V_{CE} =$ | 400 | V |
| $V_{GE} =$ | 0 / 15 | V |
| $R_{gon} =$ | 4 | Ω |
| $R_{goff} =$ | 4 | Ω |



With an inductive load at

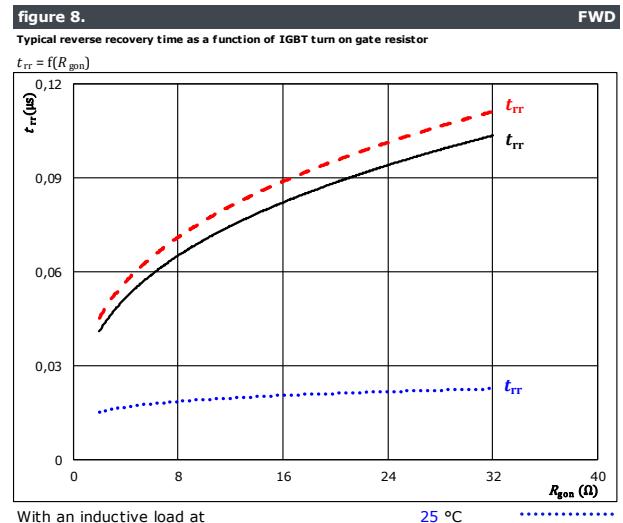
| | | |
|------------|--------|----|
| $T_j =$ | 150 | °C |
| $V_{CE} =$ | 400 | V |
| $V_{GE} =$ | 0 / 15 | V |
| $I_c =$ | 50 | A |



With an inductive load at

| | | |
|-------------|--------|---|
| $V_{CE} =$ | 400 | V |
| $V_{GE} =$ | 0 / 15 | V |
| $R_{gon} =$ | 4 | Ω |

| | | |
|--------|--------|-------|
| $T_j:$ | 25 °C | — |
| | 125 °C | — |
| | 150 °C | - - - |



With an inductive load at

| | | |
|------------|--------|---|
| $V_{CE} =$ | 400 | V |
| $V_{GE} =$ | 0 / 15 | V |
| $I_c =$ | 50 | A |

| | | |
|--------|--------|-------|
| $T_j:$ | 25 °C | — |
| | 125 °C | — |
| | 150 °C | - - - |

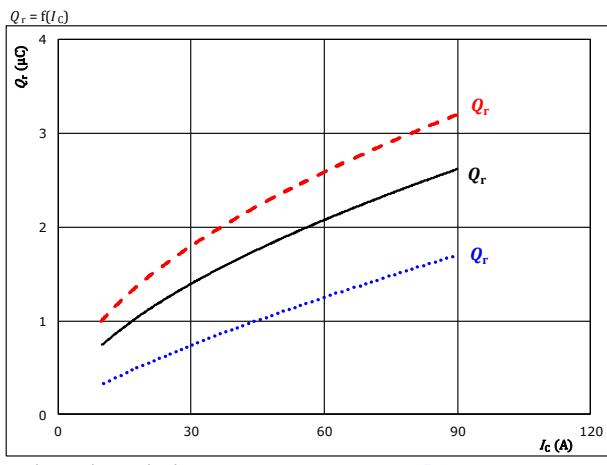


Vincotech

PFC Switching Characteristics

figure 9.

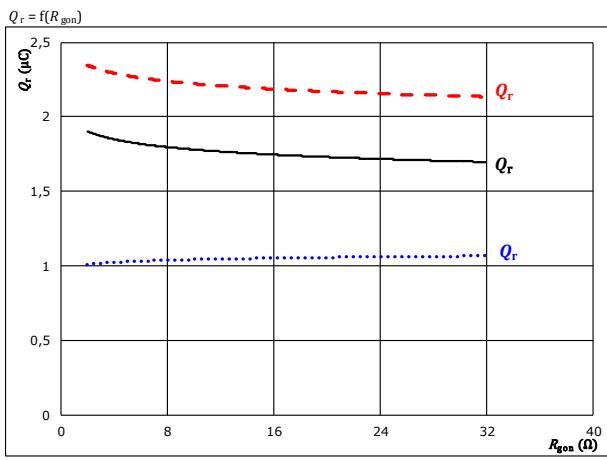
Typical recovered charge as a function of collector current



With an inductive load at
 $V_{CE} = 400$ V $T_f = 25$ °C $V_{GE} = 0 / 15$ V $T_f = 125$ °C
 $R_{gon} = 4$ Ω $V_{GE} = 150$ °C

figure 10.

Typical recovered charge as a function of IGBT turn on gate resistor

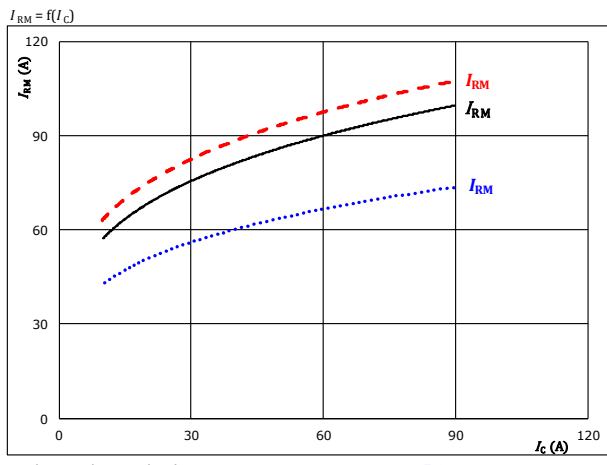


With an inductive load at
 $V_{CE} = 400$ V $T_f = 25$ °C $V_{GE} = 0 / 15$ V $T_f = 125$ °C
 $I_C = 50$ A $V_{GE} = 150$ °C

figure 11.

FWD

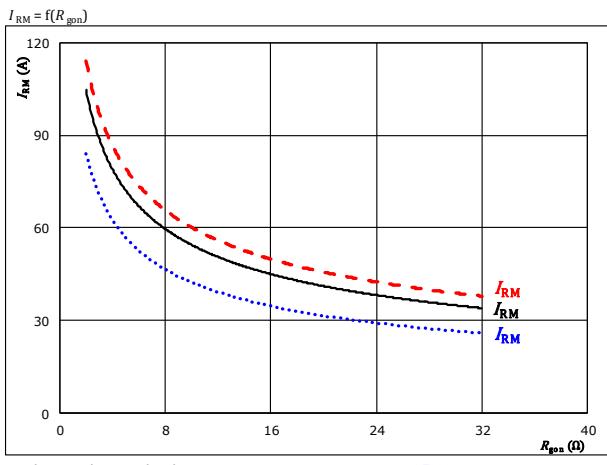
Typical peak reverse recovery current as a function of collector current



With an inductive load at
 $V_{CE} = 400$ V $T_f = 25$ °C $V_{GE} = 0 / 15$ V $T_f = 125$ °C
 $R_{gon} = 4$ Ω $V_{GE} = 150$ °C

figure 12.

Typical peak reverse recovery current as a function of IGBT turn on gate resistor



With an inductive load at
 $V_{CE} = 400$ V $T_f = 25$ °C $V_{GE} = 0 / 15$ V $T_f = 125$ °C
 $I_C = 50$ A $V_{GE} = 150$ °C



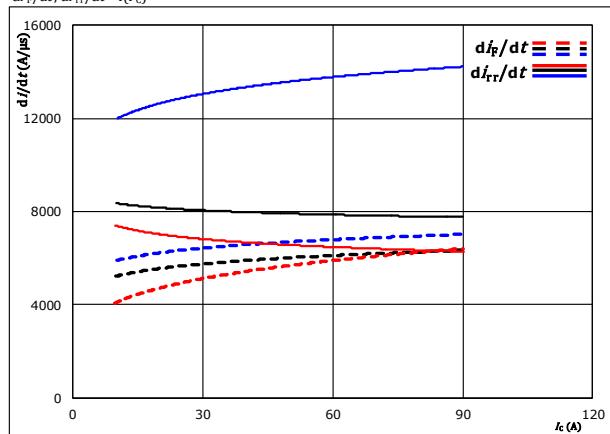
Vincotech

PFC Switching Characteristics

figure 13.

Typical rate of fall of forward and reverse recovery current as a function of collector current

$$di_F/dt, di_{rr}/dt = f(I_c)$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 400 \quad V \\ V_{GE} &= 0 / 15 \quad V \\ R_{gon} &= 4 \quad \Omega \end{aligned}$$

25 °C

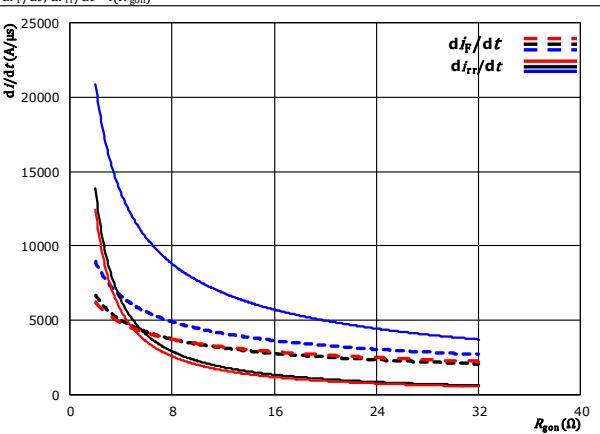
$$\begin{aligned} T_f &= 125 \text{ } ^\circ\text{C} \\ V_{GE} &= 150 \text{ } ^\circ\text{C} \end{aligned}$$

FWD

figure 14.

Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor

$$di_F/dt, di_{rr}/dt = f(R_{gon})$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 400 \quad V \\ V_{GE} &= 0 / 15 \quad V \\ I_c &= 50 \quad A \end{aligned}$$

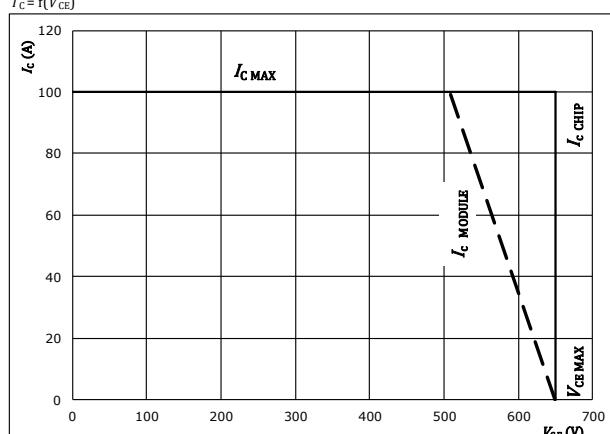
25 °C

$$\begin{aligned} T_f &= 125 \text{ } ^\circ\text{C} \\ V_{GE} &= 150 \text{ } ^\circ\text{C} \end{aligned}$$

figure 15.

Reverse bias safe operating area

$$I_c = f(V_{CE})$$



At

$$\begin{aligned} T_f &= 125 \quad ^\circ\text{C} \\ R_{gon} &= 4 \quad \Omega \\ R_{goff} &= 4 \quad \Omega \end{aligned}$$

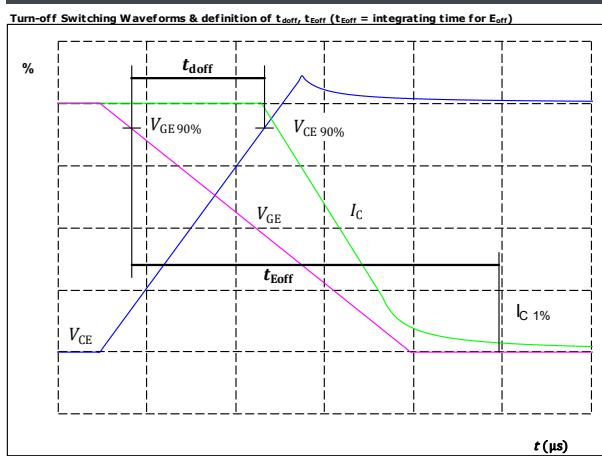


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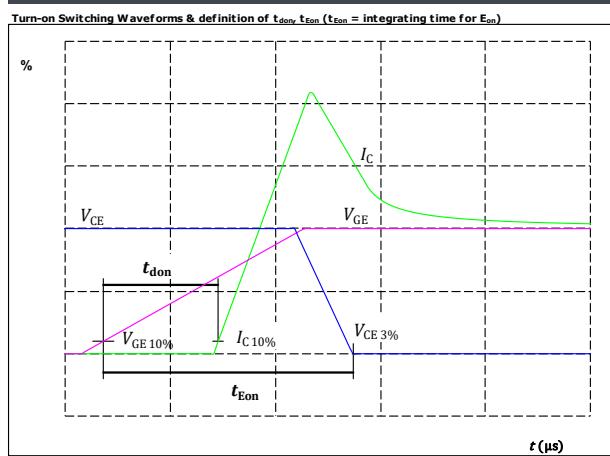
PFC Switching Definitions

General conditions

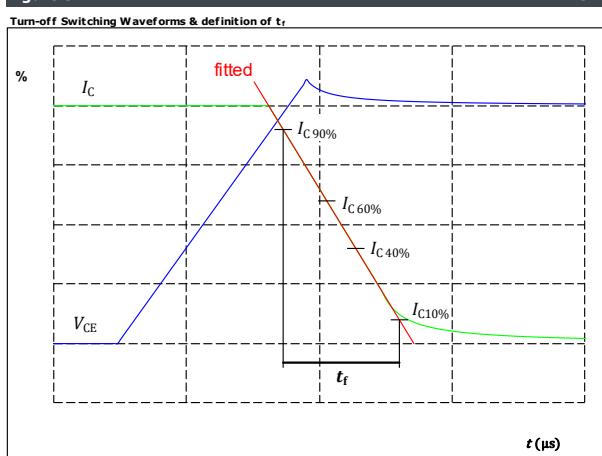
| | | |
|------------|---|--------|
| T_j | = | 125 °C |
| R_{gon} | = | 4 Ω |
| R_{goff} | = | 4 Ω |

figure 1.**IGBT**

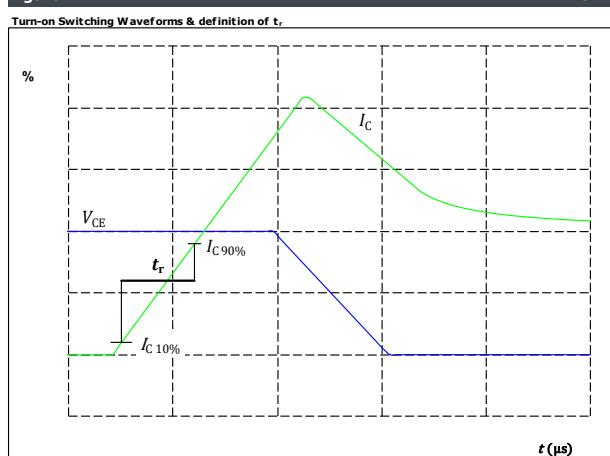
$V_{GE\ (0\%)} = 0 \text{ V}$
 $V_{GE\ (100\%)} = 15 \text{ V}$
 $V_C\ (100\%) = 400 \text{ V}$
 $I_C\ (100\%) = 50 \text{ A}$
 $t_{doff} = 97 \text{ ns}$

figure 2.**IGBT**

$V_{GE\ (0\%)} = 0 \text{ V}$
 $V_{GE\ (100\%)} = 15 \text{ V}$
 $V_C\ (100\%) = 400 \text{ V}$
 $I_C\ (100\%) = 50 \text{ A}$
 $t_{don} = 13 \text{ ns}$

figure 3.**IGBT**

$V_C\ (100\%) = 400 \text{ V}$
 $I_C\ (100\%) = 50 \text{ A}$
 $t_f = 6 \text{ ns}$

figure 4.**IGBT**

$V_C\ (100\%) = 400 \text{ V}$
 $I_C\ (100\%) = 50 \text{ A}$
 $t_r = 7 \text{ ns}$



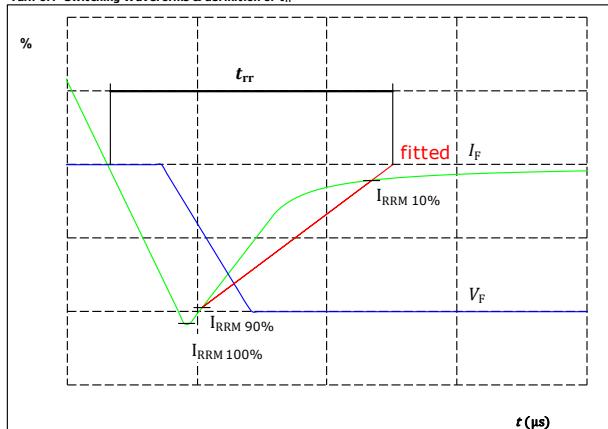
Vincotech

PFC Switching Characteristics

figure 5.

FWD

Turn-off Switching Waveforms & definition of t_{rr}

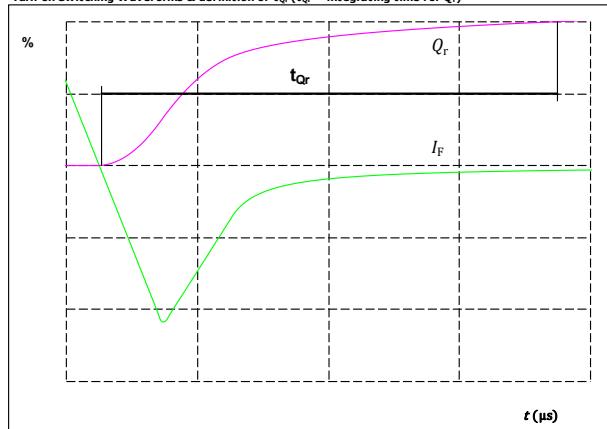


| | | |
|--------------------|-----|----|
| $V_F(100\%) =$ | 400 | V |
| $I_F(100\%) =$ | 50 | A |
| $I_{RRM}(100\%) =$ | 83 | A |
| $t_{rr} =$ | 47 | ns |

figure 6.

FWD

Turn-on Switching Waveforms & definition of t_{Qr} (t_{Qr} = integrating time for Q_r)



| | | |
|----------------|------|----|
| $I_F(100\%) =$ | 50 | A |
| $Q_r(100\%) =$ | 1,79 | μC |



10-PG06PPA050SJ01-LH54E08T

datasheet

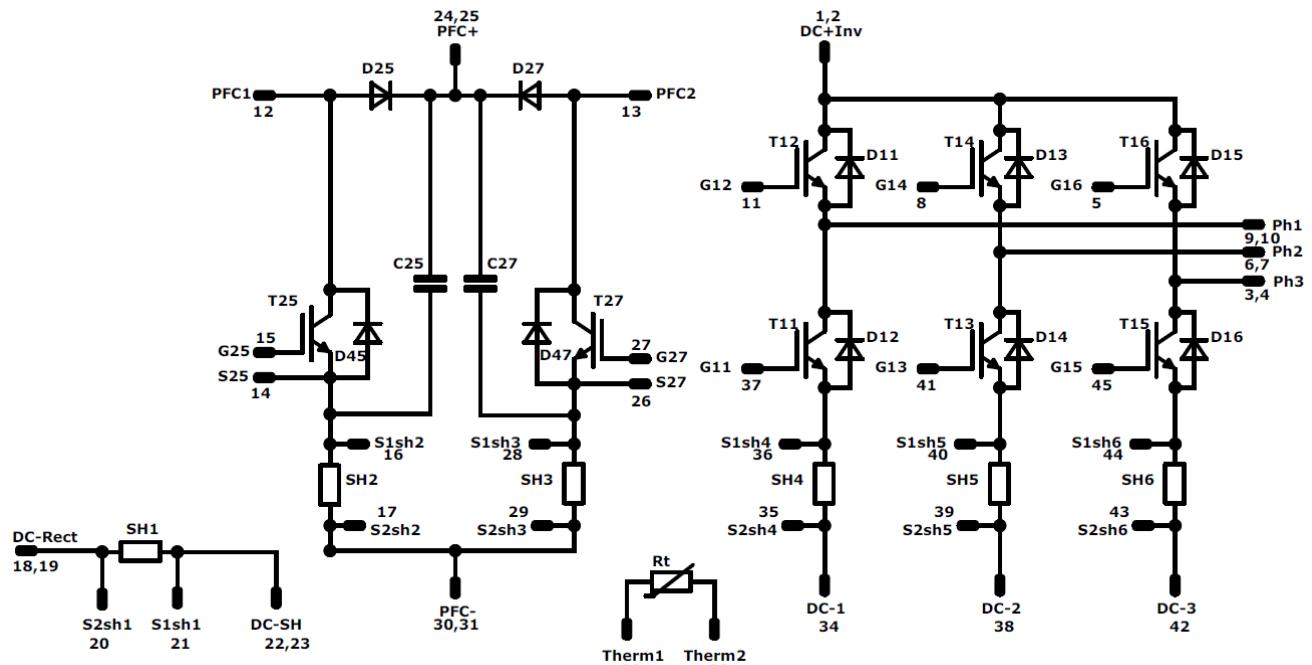
Vincotech

| Ordering Code & Marking | | | | | | | | | | | |
|--|---------------|------|----------|--------------------------------|--------------------------------|------------|-----------|--|--|--|--|
| Version | | | | Ordering Code | | | | | | | |
| without thermal paste 12mm housing with Press-fit pins | | | | 10-PG06PPA050SJ01-LH54E08T | | | | | | | |
| with thermal paste 12mm housing with Press-fit pins | | | | 10-PG06PPA050SJ01-LH54E08T-/3/ | | | | | | | |
| | | | | | | | | | | | |
| NN-NNNNNNNNNNNNN TTTTTTVV WWYY UL VIN LLLL SSSS | | | | Text | Name | | Date code | | | | |
| | | | | | NN-NNNNNNNNNNNN-TTTTTV WWYY | | UL VIN | | | | |
| | | | | Datamatrix | Type&Ver | Lot number | Serial | | | | |
| | | | | | TTTTTTVV | LLLLL | SSSS | | | | |
| | | | | | | | | | | | |
| Outline | | | | | | | | | | | |
| Pin table | | | | | | | | | | | |
| Pin | X | Y | Function | | | | | | | | |
| 1 | 52,5 | 2,7 | DC+Inv | | | | | | | | |
| 2 | 52,5 | 0 | DC+Inv | | | | | | | | |
| 3 | 46,2 | 0 | Ph3 | | | | | | | | |
| 4 | 43,5 | 0 | Ph3 | | | | | | | | |
| 5 | 43,5 | 3 | G16 | | | | | | | | |
| 6 | 37,2 | 0 | Ph2 | | | | | | | | |
| 7 | 34,5 | 0 | Ph2 | | | | | | | | |
| 8 | 34,5 | 3 | G14 | | | | | | | | |
| 9 | 28,2 | 0 | Ph1 | | | | | | | | |
| 10 | 25,5 | 0 | Ph1 | | | | | | | | |
| 11 | 22,5 | 0 | G12 | | | | | | | | |
| 12 | 0 | 0 | PFC1 | | | | | | | | |
| 13 | 0 | 6,1 | PFC2 | | | | | | | | |
| 14 | 19,5 | 6,6 | S25 | | | | | | | | |
| 15 | 22,5 | 6,6 | G25 | | | | | | | | |
| 16 | 25,5 | 8,3 | S1sh2 | | | | | | | | |
| 17 | 25,5 | 11,3 | S2sh2 | | | | | | | | |
| 18 | 0 | 16,8 | DC-Rect | | | | | | | | |
| 19 | 0 | 19,5 | DC-Rect | | | | | | | | |
| 20 | 0 | 22,5 | S2sh1 | | | | | | | | |
| 21 | 0 | 25,5 | S1sh1 | | | | | | | | |
| 22 | 0 | 28,5 | DC-SH | | | | | | | | |
| 23 | 2,7 | 28,5 | DC-SH | | | | | | | | |
| 24 | 9,8 | 25,8 | PFC+ | | | | | | | | |
| 25 | 9,8 | 28,5 | PFC+ | | | | | | | | |
| 26 | 20,7 | 16,5 | S27 | | | | | | | | |
| 27 | 20,7 | 19,5 | G27 | | | | | | | | |
| 28 | 16,9 | 23,5 | S1sh3 | | | | | | | | |
| 29 | 16,9 | 26,5 | S2sh3 | | | | | | | | |
| 30 | 20,7 | 28,5 | PFC- | | | | | | | | |
| 31 | 23,4 | 28,5 | PFC- | | | | | | | | |
| 32 | 22 | 25,5 | Therm1 | | | | | | | | |
| 33 | 22 | 22,5 | Therm2 | | | | | | | | |
| 34 | 27 | 28,5 | DC-1 | | | | | | | | |
| 35 | 33,5 | 28,5 | S2sh4 | | | | | | | | |
| 36 | 33,5 | 25,5 | S1sh4 | | | | | | | | |
| 37 | 33,5 | 22,5 | G11 | | | | | | | | |
| 38 | 36,5 | 28,5 | DC-2 | | | | | | | | |
| 39 | 43 | 28,5 | S2sh5 | | | | | | | | |
| 40 | 43 | 25,5 | S1sh5 | | | | | | | | |
| 41 | 43 | 22,5 | G13 | | | | | | | | |
| 42 | 46 | 28,5 | DC-3 | | | | | | | | |
| 43 | 52,5 | 28,5 | S2sh6 | | | | | | | | |
| 44 | 52,5 | 25,5 | S1sh6 | | | | | | | | |
| 45 | 52,5 | 22,5 | G15 | | | | | | | | |
| 46 | Not assembled | | | | | | | | | | |



Vincotech

Pinout



Identification

| Identification | | | | | |
|---------------------------------|-----------|---------|---------|--------------------------|---------|
| ID | Component | Voltage | Current | Function | Comment |
| T11, T12, T13, T14, T15, T16 | IGBT | 600 V | 50 A | Inverter Switch | |
| D11, D12, D13, D14, D15, D16 | FWD | 600 V | 30 A | Inverter Diode | |
| T25, T27 | IGBT | 650 V | 50 A | PFC Switch | |
| D25, D27 | FWD | 650 V | 50 A | PFC Diode | |
| D45, D47 | FWD | 650 V | 10 A | PFC Sw. Protection Diode | |
| SH1 | Shunt | | 63 A | Shunt | |
| SH2, SH3 | Shunt | | 32 A | PFC Shunt | |
| SH4, SH5, SH6 | Shunt | | 32 A | Inverter Shunt | |
| C25, C27 | Capacitor | 630 V | | Capacitor (PFC) | |
| Rt | NTC | | | Thermistor | |



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| Packaging instruction | | | |
|---------------------------------------|------|----------|-------------|
| Standard packaging quantity (SPQ) 100 | >SPQ | Standard | <SPQ Sample |

| Handling instruction | | | |
|---|--|--|--|
| Handling instructions for <i>flow 1</i> packages see vincotech.com website. | | | |

| Package data | | | |
|--|--|--|--|
| Package data for <i>flow 1</i> packages see vincotech.com website. | | | |

| UL recognition and file number | | | |
|---|--|--|---|
| This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website. | | |  |

| Document No.: | Date: | Modification: | Pages |
|----------------------------------|--------------|--------------------------------|--------------|
| 10-PG06PPA050SJ01-LH54E08T-D3-14 | 09 May. 2019 | Correction of I_c/I_f values | 2 |

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